

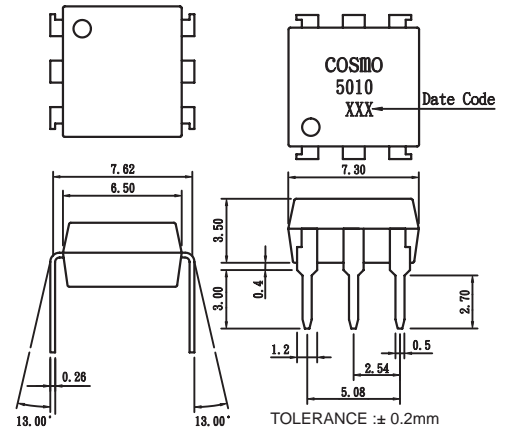
Features

1. High current transfer ratio (V_{CEO}:300V MIN)
(CTR:MIN.600% at I_F=1mA, V_{ce}=2V)
2. High isolation voltage between input and output
(Viso:5000Vrms).
3. Compact dual-in-line package.
4. Available package : DIP/ SMD/ H. (For Package Dimension please refer to page 82)

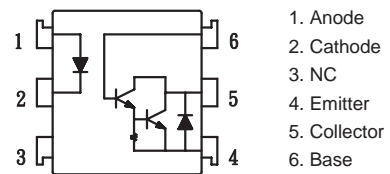
Applications

1. System appliances, measuring instruments.
2. Industrial robots.
3. Copiers, automatic vending machines.
4. Signal transmission between circuits of different potentials and impedances.
5. Telephone sets.
6. Copiers, facsimiles.
7. Interface with various power supply circuits, power distribution boards.
8. Numerical control machines.

Outside Dimension : Unit (mm)



Schematic : Top View



Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P _D	70	mW
Output	Collector-emitter voltage	V _{CEO}	300	V
	Collector-base voltage	V _{CB0}	300	V
	Emitter-base voltage	V _{EBO}	6	V
	Collector current	I _C	150	mA
	Collector power dissipation	P _C	200	mW
Total power dissipation		P _{tot}	200	mW
Isolation voltage 1 minute		Viso	5000	V _{rms}
Operating temperature		T _{opr}	-30 to +100	°C
Storage temperature		T _{stg}	-55 to +125	°C
Soldering temperature 10 second		T _{sol}	260	°C

Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F =20mA	—	1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} =0.5A	—	—	3.5	V
	Reverse current	I _R	V _R =4V	—	—	10	uA
	Terminal capacitance	C _t	V=0, f=1kHz	—	30	—	pF
Output	Collector dark current	I _{CEO}	V _{CE} =200V, I _F =0	—	—	1	uA
Transfer characteristics	Current transfer ratio	CTR	I _F =1mA, V _{CE} =2V	600	—	9000	%
	Collector-emitter saturation voltage	V _{CE (sat)}	I _F =20mA, I _C =5mA	—	—	1.5	V
	Isolation resistance	Riso	DC500V	5X10 ¹⁰	—	—	ohm
	Floating capacitance	C _f	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CC} =5V, I _C =2mA, R _L =100ohm	—	7	—	kHz
	Response time (Rise)	t _r	V _{CE} =2V, I _C =20mA, R _L =100ohm	—	60	300	us
	Response time (Fall)	t _f		—	50	250	us

Classification table of current transfer ratio is shown below.

Model NO.	CTR (%)
*KP5010 A	600 TO 2000
KP5010 B	1500 TO 4000
KP5010 C	3000 TO 6000
*KP5010 D	5000 TO 9000
KP5010 E	600 TO 9000

*SPECIAL OPTION

Fig.1 Current Transfer Ratio vs. Forward Current

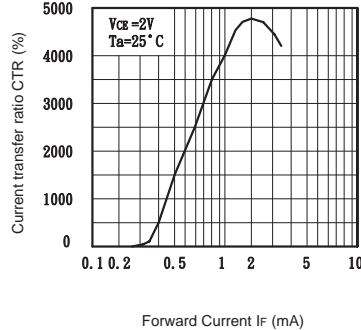


Fig.2 Collector Power Dissipation vs. Ambient Temperature

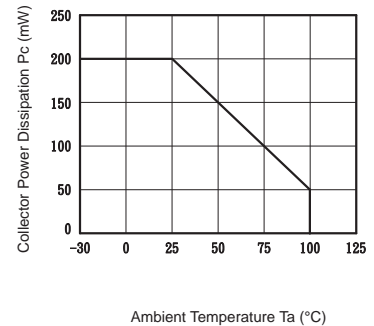


Fig.3 Collector Dark Current vs. Ambient Temperature

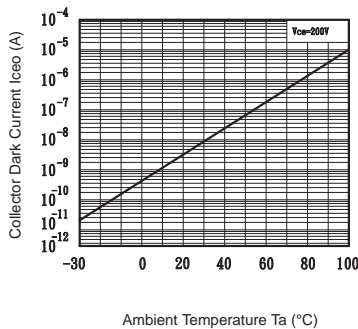


Fig.4 Forward Current vs. Ambient Temperature

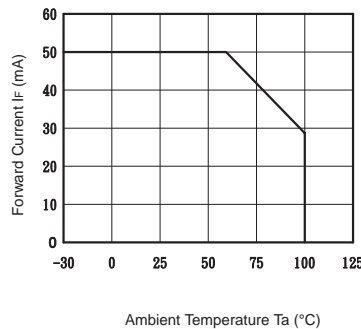


Fig.5 Forward Current vs. Forward Voltage

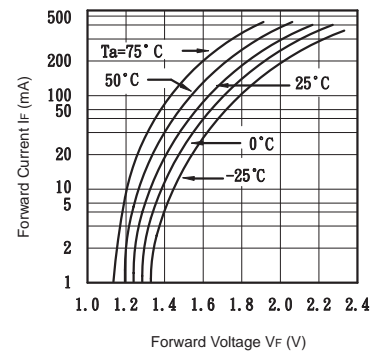


Fig.6 Collector Current vs. Collector-emitter Voltage

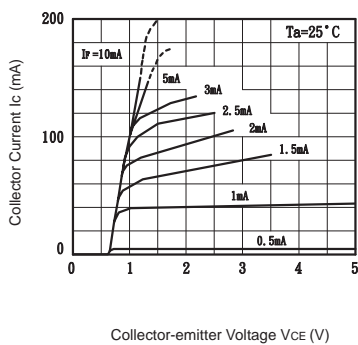


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

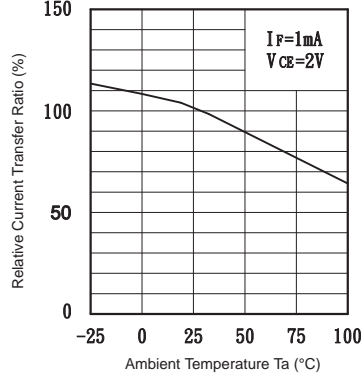


Fig.8 Collector-emitter Saturation Voltage vs. Forward Current

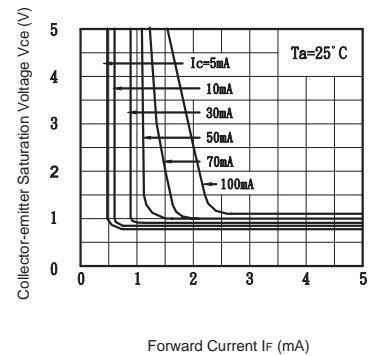


Fig.9 Response Time vs. Load Resistance

